

Ultra Low Capacitance Array for ESD Protection

The MESD0524P2 provides a typical line to line capacitance of 0.15pF between I/O pins and low insertion loss up to 3GHz providing greater signal integrity making it ideally suited for HDMI applications, such as Digital TVs, DVD players, Computing, set-top boxes and MDDI applications in mobile computing devices.

It has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events), and EFT (electrical fast transients).

Features

- Protects two or four I/O lines
- Low capacitance:0.15pf Typical between I/O channel
- Working voltages: 5.5V
- Low leakage current
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant

Main applications

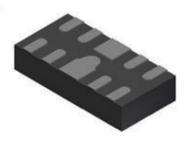
- High Definition Multi-Media Interface (HDMI1.3/1.4/2.0)
- Digital Visual Interface (DVI)
- Display Port Interface
- Serial ATA
- PCI Express
- USB 1.1/2.0/3.0/3.1/OTG
- IEEE 1394 Firewire Ports
- Projection TV Monitors and Flat Panel Displays
- Notebook Computers
- Set Top Box
- Projection TV

Protection solution to meet

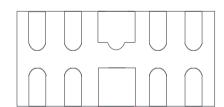
- IEC61000-4-2 (ESD) ±20kV (air), ±20kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 3.5A (8/20µs)

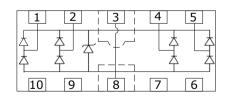
Ordering Information

Device	Marking	Qty per Reel	Reel Size
MESD0524P2	0524P	3000	7 Inch



DFN2510











Maximum ratings (Temp=25°C Unless Otherwise Specified)					
Parameter	Symbol	Value	Unit		
Peak Pulse Power (tp=8/20μs waveform)	P_{PPP}	45	Watts		
Peak Pulse Current(tp=8/20μs waveform)	I_{PP}	3.5	A		
ESD Rating per IEC61000-4-2: Contact		20	KV		
Air		20	K V		
Lead Soldering Temperature	$T_{ m L}$	260 (10 sec.)	°C		
Operating Temperature Range	$T_{ m J}$	-55 ~ 150	°C		
Storage Temperature Range	T_{STG}	-55 ~ 150	°C		

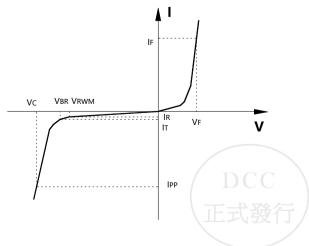
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Non-repetitive current pulse, per Figure 1.

Electrical characteristics (Temp=25°C Unless Otherwise Specified)							
Symbol	Parameter	Conditions	Min. Typ.		Max.	Units	
V_{RWM}	Reverse Working Voltage	Any I/O to Ground			5.5	V	
V	Reverse Breakdown Voltage	IT = 1mA,	6.0			V	
V_{BR}		Any I/O to Ground	6.0			V	
Ţ	Daniera Laglace Comunit	$V_{RWM} = 5V$,			0.5	μΑ	
I_R	Reverse Leakage Current	Any I/O to Ground					
V_{F}	Diode Forward Voltage	IF = 15mA		0.85	1.2	V	
		$I_{PP} = 1A$, $tp = 8/20 \mu s$,		8.6	9.8	V	
X 7	Classica Value	any I/O pin to Ground					
$V_{\rm C}$	Clamping Voltage	Iamping Voltage $I_{PP} = 3.5A$, tp =8/20 μ s,		11.4	1.5	3.7	
		any I/O pin to Ground		11.4	15	V	
D.1	1	positive transient(8/20us)		0.48		0	
Rdyn	dynamic resistance	negative transient(8/20us)		0.35		Ω	
		$V_R = 0V, f = 1MHz,$	0.25	F			
C	Junction Capacitance	between I/O pins		0.15	0.25	pF	
C_{J}		$V_R = 0V$, $f = 1MHz$,		0.2	0.35	pF	
		any I/O pin to Ground		0.2			

Junction capacitance is measured in VR=0V,F=1MHz

Symbol	Parameter		
V_{RWM}	Working Peak Reverse Voltage		
V_{BR}	Breakdown Voltage @ I _T		
$V_{\rm C}$	Clamping Voltage @ I _{PP}		
I_{T}	Test Current		
I_{RM}	Leakage current at V _{RWM}		
I_{PP}	Peak pulse current		
Co	Off-state Capacitance		
C_{J}	Junction Capacitance		

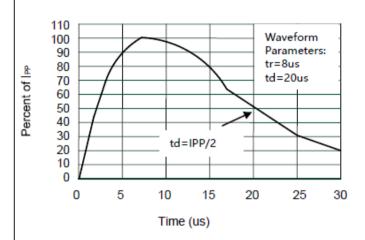


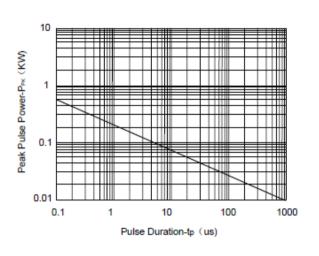


^{*}Other voltages may be available upon request.

Force mos

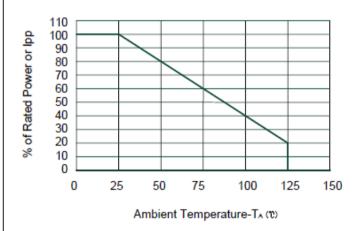
Typical electrical characterist applications

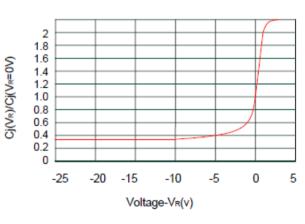




Pulse Waveform

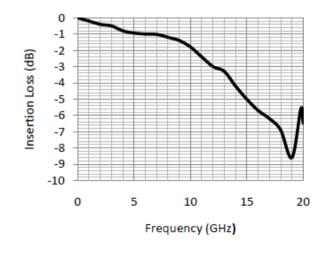
Non-Repetitive Peak Pulse Power vs. Pulse Time

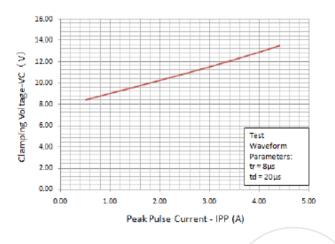




Power Derating Curve

Junction Capacitance vs. Reverse Voltage





Insertion Loss S21

Clamping Voltage vs. Peak Pulse Current

Force mos

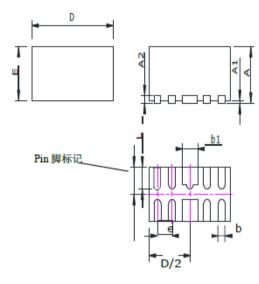
Package Information

DFN2510

Mechanical Data

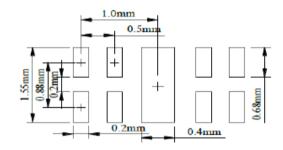
Case:DFN2510

Case Material: Molded Plastic. ULFlammability

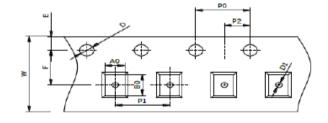


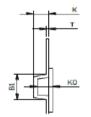
DIM	Millir	meters		
DIM	Min	Max		
A	0.45	0.65		
A1	0.05REF			
A2	0.15REF			
b	0.15	0.25		
b1	0.30	0.50		
D	2.424	2.576		
E	0.924	1.076		
e	0.50REF			
L	0.30	0.45		

Recommended Pad outline



DFN2510 Reel Dim





Package	Chip Size (mm)	Pocket Size B0×A0×K0(mm)	Tape Width	Reel Diameter	Quantity Per Reel	P0	P1
DFN2510	2.50×1.00×0.60	2.70×1.20×0.80	8mm	178mm(7")	3000	4mm	4mm
D0	D1	E	F	K	T	W	
1.5mm	0.2mm	1.75mm	3.5mm	0.65mm	0.2mm	8n	nm _



May,2019-Ver1.0